Elpida Memory Begins Mass Production of DDR2 SDRAM Using 0.10-micron Process Technology

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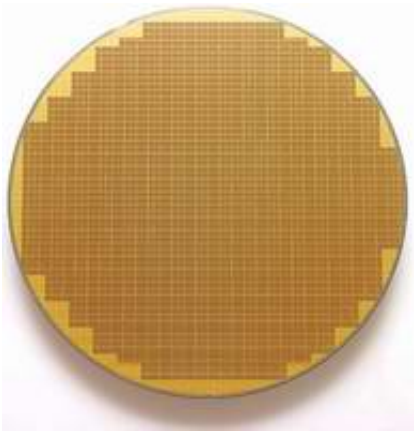

Elpida Memory, Inc (Elpida), Japan's leading global supplier of Dynamic Random Access Memory (DRAM), today announced that it will begin mass production of DDR2 SDRAM using **advanced 0.10-micron process technology** in August 2004. The first products slated for manufacturing utilizing 0.10-micron process technology include high-performance, high-density DRAM products such as DDR2-533 and DDR2-667.

"Elpida strives to offer the industry stable production of high-performance DRAM products," said Yukio Sakamoto, president of

Elpida Memory. "Our ability to mass manufacture 0.10-micron DRAM enables us to meet increased demand for advanced DDR2 SDRAM as the industry transitions from DDR to DDR2 architecture."

Elpida plans to increase production capacity of 0.10-micron based products to more than 50% of their 300 mm wafer line capacity by January 2005.

Source: Elpida Memory, Inc